

Biot-Savart 畢奧特-薩爾發定律

1. 導體某一段 ΔL 對外一點之磁場強度 $H_p = \frac{I \cdot \Delta L \cdot \sin \theta}{4\pi r^2}$

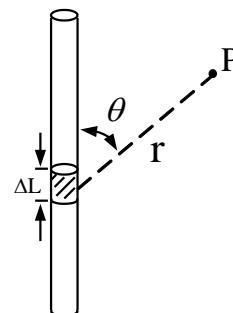
證明：

P 處放置一單位磁極 M，距 r 米處之球型表面磁通密度 $B = \frac{M}{4\pi r^2}$

載 I 安培導體置於球表面其受力為

$$F = B \cdot I \cdot \Delta L \cdot \sin \theta = \frac{M}{4\pi r^2} I \cdot \Delta L \cdot \sin \theta$$

$$H_p = \frac{F}{M} = \frac{I \cdot \Delta L \cdot \sin \theta}{4\pi r^2}$$



2. 有限長度導體對外一點之磁場強度 $H_p = \frac{I}{4\pi R} (\sin \alpha_1 + \sin \alpha_2)$

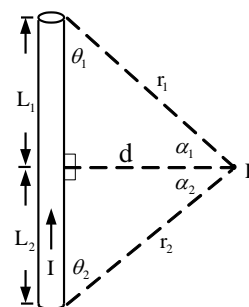
證明：

$$l = R \cot \theta$$

$$dl = R \csc^2 \theta d\theta$$

$$H_p = \int \frac{I \cdot \sin \theta}{4\pi r^2} dl = \int_{\theta_2}^{\theta_1} \frac{I \cdot \sin \theta \cdot R \csc^2 \theta}{4\pi (R/\sin \theta)^2} d\theta = \int_{\theta_2}^{\theta_1} \frac{I \cdot \sin \theta}{4\pi R} d\theta = \frac{I}{4\pi R} [\cos \theta_1 + \cos \theta_2]$$

$$= \frac{I}{4\pi R} [\sin \alpha_1 + \sin \alpha_2]$$

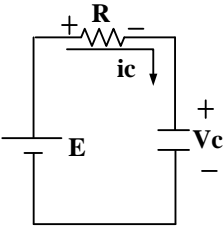
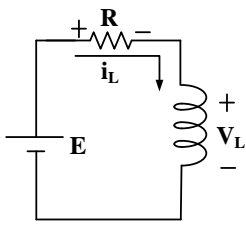


3. 無限長導線對外一點之磁場強度 $H_p = \frac{I}{2\pi R}$

4. 圓形線圈

$$H_p = \frac{I \cdot \Delta L \cdot \sin \theta}{4\pi r^2} = \frac{I \cdot 2\pi r \cdot \sin 90^\circ}{4\pi r^2} = \frac{I}{2r} \text{ (單匝)}$$

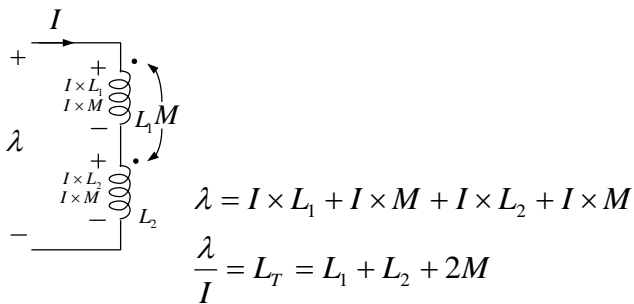
$$H_p = \frac{NI}{2r} \text{ (N匝)}$$

	電場	磁場
庫倫定律	$\vec{F} = K \frac{Qq}{d^2}$ $(K = \frac{1}{4\pi\epsilon_0\epsilon_r} = 9 \times 10^9 (\epsilon_0 = 8.85 \times 10^{-12}))$	$\vec{F} = K \frac{Mm}{d^2}$ $(K = \frac{1}{4\pi\mu_0\mu_r} = 6.33 \times 10^4 (\mu_0 = 4\pi \times 10^{-7}))$
強度	$\vec{E} = \frac{F}{q} = K \frac{q}{d^2}$	$\vec{H} = \frac{F}{m} = K \frac{M}{d^2}$
動勢	$V = \frac{W}{q} = \frac{F \cdot d}{q} = K \frac{q}{d}$	$J = \frac{W}{m} = K \frac{M}{d}$
高斯定律	$\Phi(\text{庫倫}) = q(\text{庫倫})[\text{MKS}]$ $\Phi(\text{線}) = 4\pi q(\text{靜庫})[\text{CGS}]$	$\varphi(\text{韋伯}) = m(\text{韋伯})[\text{MKS}]$ $\varphi(\text{線}) = 4\pi m(\text{靜磁})[\text{CGS}]$
密度	$D = \frac{\Phi}{A} = \epsilon E$	$B = \frac{\phi}{A} = \mu H$
定律	$V = IR$	$J = NI = \phi R = Hl \quad (R = \frac{l}{\mu A})$
結構	$R = \rho \frac{l}{A} \quad C = \epsilon \frac{A}{d}$	$R = \frac{l}{\mu A}$
公式	$Q = CV = It$	$\lambda = LI = N\phi = Et \quad (E = N \frac{\Delta\phi}{\Delta t})$
電路分析	$i_c = C \frac{dv_c}{dt}$ 	$v_L = L \frac{di_L}{dt}$ 
能量	$W = \frac{1}{2} QV = \frac{1}{2} CV^2 = \frac{1}{2} \frac{Q^2}{C}$	$W = \frac{1}{2} \lambda I = \frac{1}{2} N\phi I = \frac{1}{2} LI^2$
單位換算	1 牛頓(Nt) = 10^5 達因(dyne) 1 庫倫(C) = 3×10^9 靜庫(S. C.) 1 伏特(V) = $\frac{1}{300}$ 靜伏(S. V.) 1 焦耳(J) = 10^7 爾格(erg)	1 韋伯(wb) = 10^8 馬克斯威爾(Maxwell) $= 10^8$ 線(line) = $\frac{1}{4\pi} \times 10^8$ 靜磁 1 wb/m^2 = 1 特斯拉(Tesla) = 10^4 高斯(Gauss)

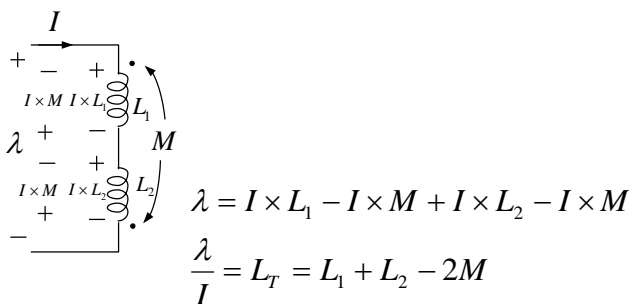
考慮互感之等效電感量計算

將磁通鏈 λ 類比為電壓 V ，電感類比為電阻，利用驅動點阻抗法觀念，求串聯及並聯考慮互感等效電感值。

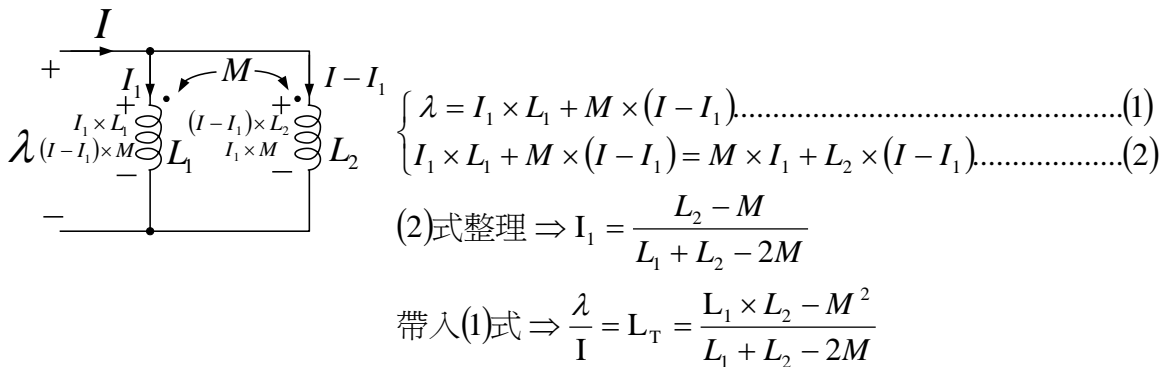
1. 串聯互助



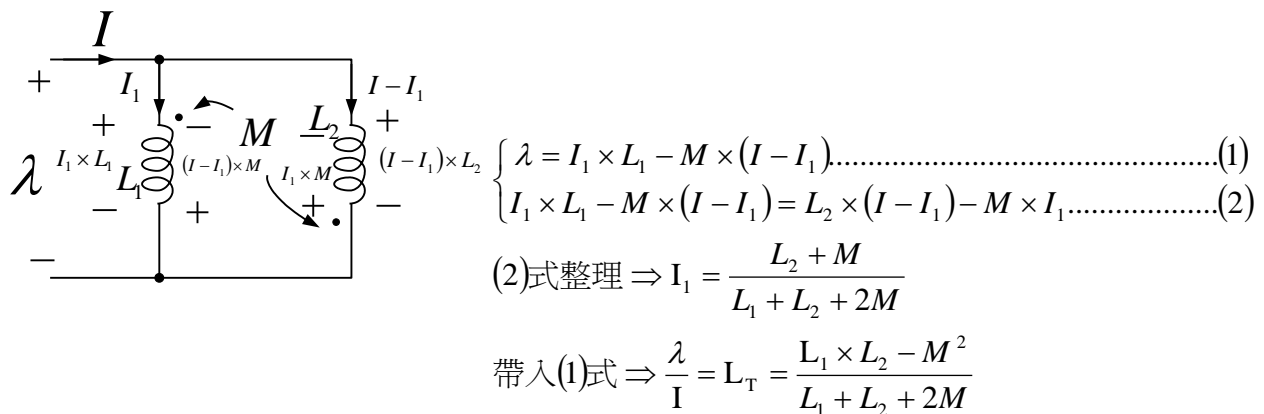
2. 串聯互消



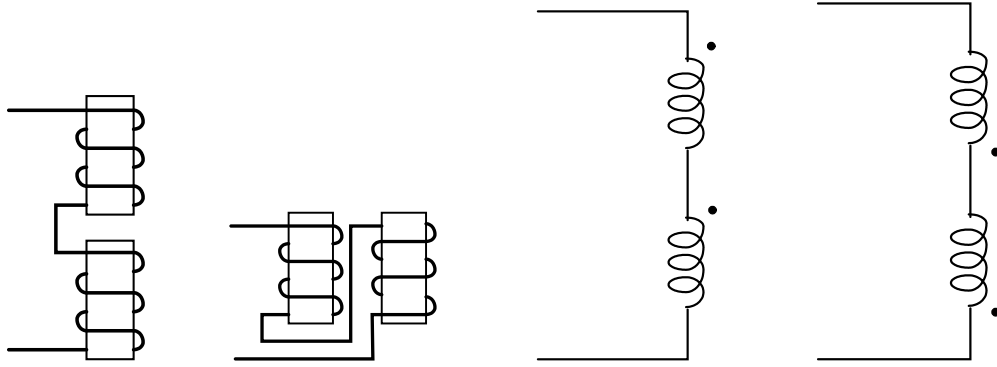
3. 並聯互助



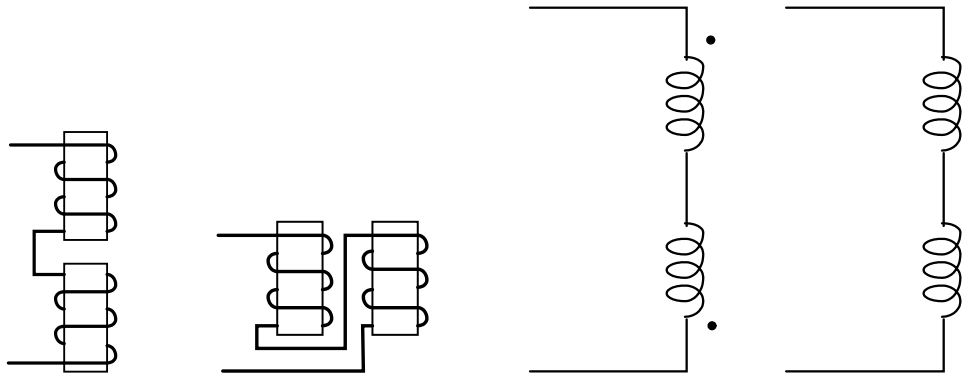
4. 並聯互消



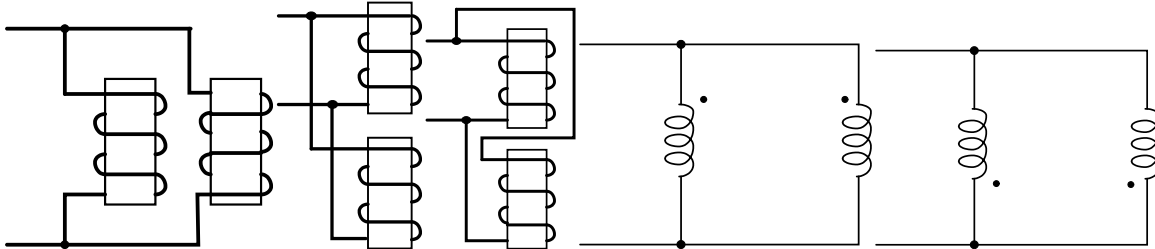
5. 串聯互助型式的電路連接與電路符號



6. 串聯互消型式的電路連接與電路符號



7. 並聯互助型式的電路連接與電路符號



8. 並聯互消型式的電路連接與電路符號

